TOSHIBA Transistor Silicon NPN Triple Diffused Type

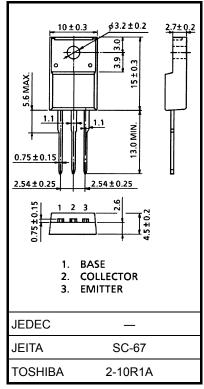
2SC5459

Switching Regulator Applications High-Voltage Switching Applications DC-DC Converter Applications

- High-speed switching: $t_f = 0.3 \ \mu s \ (max) \ (I_C = 1.2 \ A)$
- High collector breakdown voltage: V_{CEO} = 400 V
- High DC current gain: $h_{FE} = 20$ (min) (I_C = 0.3 A)

Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	600	V	
Collector-emitter voltage		V _{CEO}	400	V	
Emitter-base voltage		V _{EBO}	7	V	
Collector current	DC	Ι _C	3	А	
	Pulse	I _{CP}	5	A	
Base current		Ι _Β	1	А	
Collector power dissipation	Ta = 25°C	De	2.0	W	
	Tc = 25°C	P _C	25		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

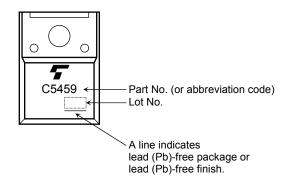
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm

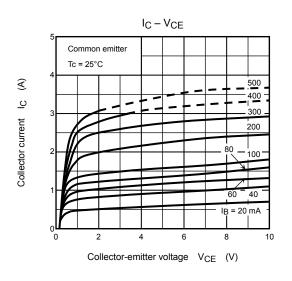
Electrical Characteristics (Tc = 25°C)

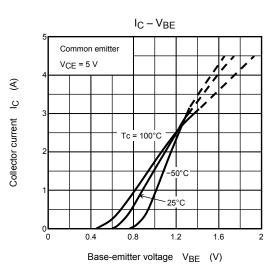
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Collector cut-off current		I _{CBO}	V _{CB} = 480 V, I _E = 0	_	_	100	μA	
Emitter cut-off current		I _{EBO}	V _{EB} = 7 V, I _C = 0		_	10	μA	
Collector-base breakdown voltage		V (BR) CBO	I _C = 1 mA, I _E = 0	600	_	_	V	
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	400	_	_	V	
DC current gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 mA	13	_	_		
		h _{FE (2)}	V _{CE} = 5 V, I _C = 0.3 A	20	—	—		
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = 1.2 A, I _B = 0.15 A	_	—	1.0	V	
Base-emitter saturation voltage		V _{BE (sat)}	I _C = 1.2 A, I _B = 0.15 A	_	—	1.3	V	
Switching time	Turn-on time	tr	$V_{CC} \approx 360 \text{ V}$ Output	_	_	0.5		
	Storage time	t _{stg}		_	_	2.0	μs	
	Fall time	t _f	/ // I _{B1} = 0.15 A, I _{B2} = −0.3 A, duty cycle ≤ 1%	_	_	0.3		

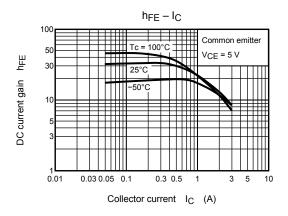
Marking

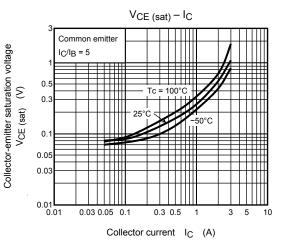


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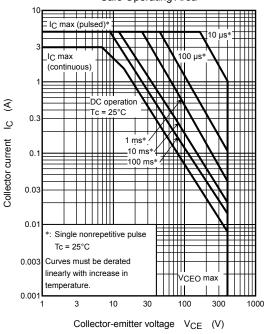


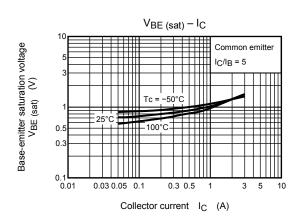












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